

MBR20H100CT, MBRF20H100CT, MBRB20H100CT

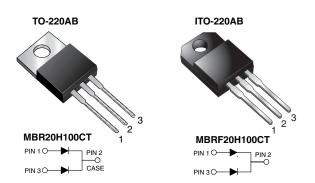
Vishay General Semiconductor

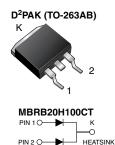
HALOGEN

FREE

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance





LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V_{RRM}	100 V				
I _{FSM}	250 A				
I _R	4.5 μA				
V_{F}	0.64 V				
T _J max.	175 °C				
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)				
Circuit configurations	Common cathode				

FEATURES

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- · Low leakage current
- · High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D²PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - RoHS-compliant, halogen-free, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR20H100CT MBRF20H100CT MBRB20H100CT	UNIT		
Maximum repetitive peak reverse voltage		V_{RRM}	100			
Working peak reverse voltage		V_{RWM}	100	V		
Maximum DC blocking voltage		V_{DC}	100			
Maximum average forward rectified current	total device	I _{F(AV)}	20	А		
waximum average forward rectilled current	per diode		10			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	250	А		
Peak repetitive reverse current per diode at $t_p = 2.0 \mu s$, 1 kHz		I _{RRM}	1.0			
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs		
Operating junction and storage temperature range		T _J . T _{STG}	-65 to +175	°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500	V		



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 10 A	T _C = 25 °C	0.77	V	
		I _F = 10 A	T _C = 125 °C	0.64		
		I _F = 20 A	T _C = 25 °C	0.88		
		I _F = 20 A	T _C = 125 °C	0.73		
Maximum reverse current at working peak reverse voltage per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	4.5	μΑ	
			T _J = 125 °C	6.0	mA	

Notes

 $^{(1)}$ Pulse test: 300 μ s pulse width, 1 % duty cycle

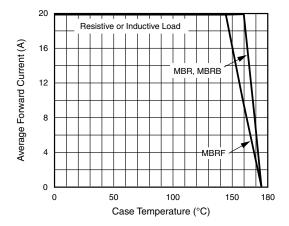
(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR20H100CT	MBRF20H100CT	MBRB20H100CT	UNIT	
Typical thermal resistance per diode	$R_{\theta JC}$	2.0	5.8	2.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR20H100CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF20H100CT-E3/45	1.99	45	50/tube	Tube		
D ² PAK (TO-263AB)	MBRB20H100CT-M3/I	1.35	I	800/reel	Tape and reel		

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)



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Fig. 1 - Forward Current Derating Curve

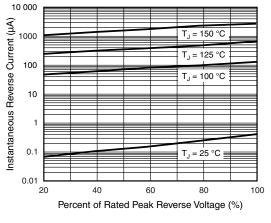


Fig. 4 - Typical Reverse Characteristics Per Diode

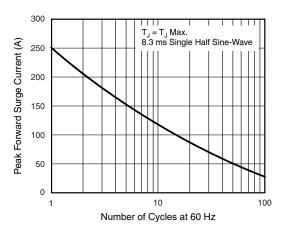


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

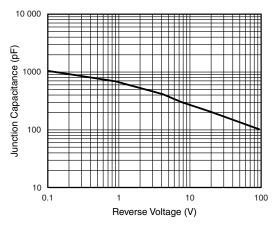


Fig. 5 - Typical Junction Capacitance Per Diode

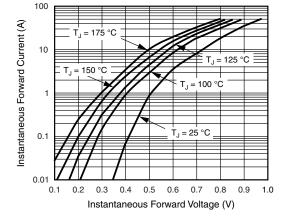


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

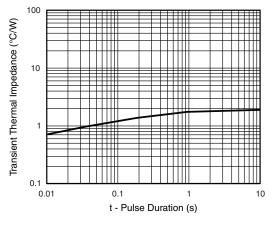


Fig. 6 - Typical Transient Thermal Impedance Per Diode

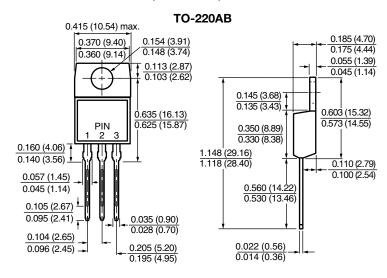


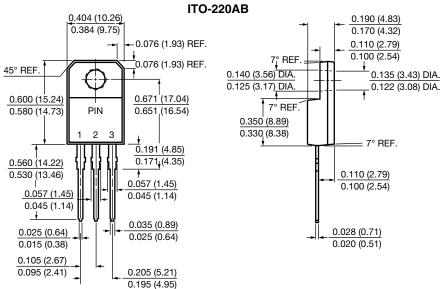


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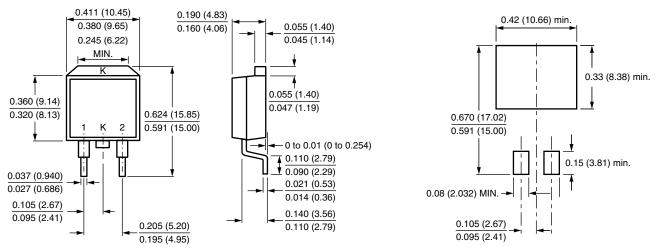
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





D²PAK (TO-263AB)

Mounting Pad Layout



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